Tw in Boundaries and Heat Capacity of a Crystal

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A bstract

The in uence of twin boundaries on the heat capacity and di use scattering in a crystal is described within the fram ework of a macroscopic dynamic theory. c 2005 Pleiades Publishing, Inc.

A chievem ents of the modern nanotechnologies in the synthesis of structures of arbitrary dimensions set the important task of studying natural low – dimensional formations in crystals, such as dislocations and domain walls, and the in uence of such objects on the mechanical and kinetic properties of materials. This paper shows that coherent twin boundaries can significantly in uence the thermodynamic properties of crystals.

Consider an elastic continuous medium containing a defect that acts as the source of a plastic deformation eld. A local change in position of the surface of this defect will modify the mism atch between the defect and environment. In the case of a planar defect, this is manifested by the motion of mist dislocations. The resulting congurational or surface forces act so as to bring the defect boundary to an equilibrium state, while the mismatch becomes (due to inertial properties of the medium) a source of elastic waves. Considering the total deformation of the crystal $u_{\rm im}$ in the presence of the structural defect as comprising the elastic "im and plastic $s_{\rm im}$ components, the Lagrangian of the elastic continuum can be written as

$$L = \frac{1}{2}^{Z} \operatorname{drdt} (\underline{u}_{i})^{2} (u_{ik} \quad s_{ik})_{ik \, lm} (u_{lm} \quad s_{lm}) : \qquad (1)$$

Let us consider the coherent boundary as an independent object in the crystal possessing its own dynamical variable & r_{jj} ; trepresenting a deviation of the boundary relative to the habit plane. Then, writing the plastic deformation caused by this deviation as

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$$s_{ij} = \& r_{jj}$$
; t (z) [S_{ij}]

substituting this expression into Lagrangian (1), and considering variations over the dynamical variables u_i (r;t) and $\& r_{jj}$;t, we eventually obtain a system of dimenstial equations [1]

$$u_{i} \quad _{ik lm} \ \theta_{k1}^{2} u_{m} + \theta_{k} \quad _{ik}^{s} \ (z) \& r_{jj}; t = 0$$

$$\int_{ik}^{s} \theta_{k} u_{m} \quad ^{s} \ (z) \& r_{jj}; t = 0$$

$$\vdots \qquad \vdots$$

These equations have a self-consistent solution under the condition provided by the dispersion relation [2]

$$\frac{q_{y}^{2}}{q_{jj}^{2}} \frac{!^{2}=c_{t}^{2}}{!^{2}=c_{t}^{2}} + \frac{4q_{x}^{2}}{!^{2}=c_{t}^{2}} q_{jj}^{2} \frac{!^{2}=c_{t}^{2}}{q_{jj}^{2}} \frac{q_{z}^{2}}{!^{2}=c_{t}^{2}} q_{jj}^{2} \frac{!^{2}=c_{t}^{2}}{q_{jj}^{2}} = 0:$$
(2)

Here, it is assumed that the habit plane of the boundary is perpendicular to the 0z axis, $[S_{ik}] = 1=2$ $(n_iS_k + n_kS_i)$ is the o set of the plastic deform ation tensor on the pas- sage through the boundary, $n_i = (0;0;1)$ is vector of the normal to the boundary, $S_i = (S_x;0;0)$ is the vector of the boundary displacement, and $s = S_{ik} s_{ik} m S_{ik} = S_{ik} s_{ik}$. The roots of dispersion equation (2) determine a relation between the eigenvector q_{ij} and the intrinsic frequency ! of bending oscillations of the boundary $[\beta]$: ! = (') qq_{ij} (g.1).

First, let us calculate the phonon heat capacity of a crystal [4]. The E instein approximation for this problem stipulates a linear dependence of the wave frequency ! on the wave vector q. U sing Eq. (2) it is also possible to take into account the in uence of a nonlinear dispersion related to the presence of a planar defect in the crystal studied. The number of eld oscillators with the wavenum bers below q can be determined as

N (!) =
$$\int_{0}^{Z^{q}} dq_{jj} = \int_{0}^{|-g_{t-1}'|} q dq d' = \frac{!^{2}}{2c_{t}^{2}} \int_{0}^{Z^{-2}} \frac{d'}{2(t')} = \frac{!^{2}}{2c_{t}^{2}} \frac{1}{2}$$

where = 1.074. Then, the D ebye frequency $!_0$ for the bound phonon states is

$$!_{0}^{2} = \frac{4N c_{t}^{2}}{3} = \frac{!^{2}}{3};$$

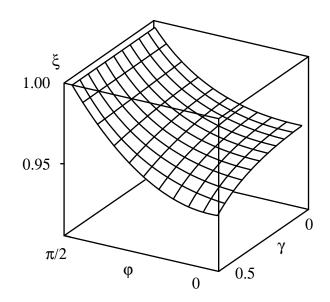


Figure 1: Dependence of the $= !=(qq_{jj})$ on angle $' = A \tan(S_y=S_x)$ and $= q_t=c_1$.

where ! is the D ebye frequency of the bulk waves. Such a considerable decrease in the D ebye frequency of the twin boundary is related to softening of the phonon m odes accompanying the displacement of atoms in the crystal lattice along the direction of the shear vector S_i .

U sing the dispersion relation (2), we obtain the average energy of localized oscillations at low temperatures ($T << T_0$) in the D ebye approximation:

$$hE_{0}i = \int_{0}^{2} \frac{h!}{\exp \frac{h!}{kT}} dN \quad (!) = \frac{h}{c_{t}^{2}} \frac{1}{2} \cdot \int_{0}^{3} 2 \quad (3) = \frac{1}{p} \frac{1}{3} hE \quad i;$$

where (3) = 1.202057 is the R iam ann zeta function and hE i is the average energy of the bulk waves in the defect-free crystal.

The heat capacity is de ned as $c_v^0 = 0E = 0T$. However, in our case, it is convenient to calculate the ratio of this quantity to the heat capacity of the defect-free crystal:

$$\frac{c_v^0}{c_v} = \frac{@e_0 = @T}{@e_e = @T} = \frac{@e_0}{@e_e} = \frac{p_1}{3} \text{ or } c_v^0 = \frac{p_v^0}{3}.$$

Evidently, a decrease in the heat capacity is related to two factors: (i) a threefold decrease in the number of bulk oscillatory modes of the crystal and

(ii) the anisotropic velocity of the surface wave packet propagating along the tw in boundary.

The presence of a single coherent tw in boundary in the crystal does not in uence the positions of electron or X -ray di raction relections An ensemble of parallel tw ins will only lead to the appearance of superstructure satellites. However, a change in the spectrum of crystal oscillations in the vicinity of the tw in boundary leads to a signi cant decrease in the total intensity of the Born scattering as a result of an increase in the di use scattering component [5].

Considering the therm all oscillations of atom s at the twin boundary as a system of elastic standing waves obeying relation (2), the in uence of these oscillations on the intensity of selective maxim a can be described in term s of the D ebyeW aller factor

$$2M = \frac{16^2 h u^2 i \sin^2 \#}{3}$$

Here, the m ean square deviation of atom s in the crystal can be expressed via the above relation for the average energy as

$${}^{D}u_{0}^{2} = {}^{Z}_{0} \frac{E_{0}}{!^{2}} dN \quad (!) = {}^{Z}_{0} \frac{h}{\exp \frac{h!}{kT}} \frac{dN \quad (!)}{!} = {}^{D}\frac{D}{3} {}^{D}u^{2} :$$

Similar to the case considered above, the presence of a coherent twin boundary in the crystal changes the observed e ect by a factor of 3 1.8.

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